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ON Semiconductor®

FAN256 — Dual Low Voltage Comparator

Features

- Low Supply Current: I_{DD}=7µA (Typical)
- Single Pow er Supply Operation
- Wide Common-Mode Input Voltage Range: Rail-to-Rail
- Push-Pull Output Circuit
- Low Input Bias Current
- Internal Hysteresis
- Packaged in MicroPak™ 8 (1.6mm x 1.6mm)

Applications

- Mobile Phones
- Alarm and Security Systems
- Personal Digital Assistants

Description

The FAN256 is a low-power, dual comparator that typically consumes less than 10 μ A supply current per comparator. Guaranteed to operate at a low voltage of 1.6V and fully operational up to 5.5V, it is convenient for use in 1.8, 3.0V, and 5.0V systems.

The FAN256 has a complementary push-pull P- and N-channel output stage capabile of driving a rail-to-rail output swing with a load ranging up to 5.0mA.

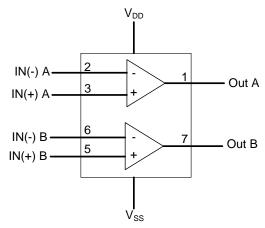


Figure 1. Functional Diagram

Ordering Information

Part Number	Top Mark	Operating Temperature Range	Package	Packing Method
FAN256L8X	CP	-40 to 85°C	8-Lead, MicroPak™ 1.6mm x 1.6mm Package	5000 Units on Tape and Reel

Pin Configuration

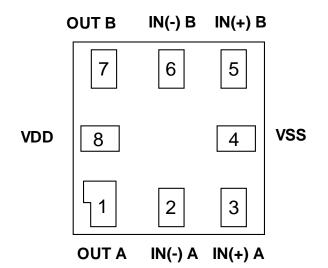
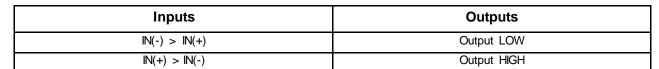


Figure 2. Pin Configuration (Top Through View)

Pin Definitions

Pin#	Name	Description		
1	OUT A	Comparator A Output		
2	IN(-) A	Inverting Input of Comparator A		
3	IN(+) A	Non-Inverting Input of Comparator A		
4	VSS	Negative Supply Voltage		
5	IN(+) B	Non-Inverting Input of Comparator B		
6	IN(-) B	Inverting Input of Comparator B		
7	OUT B	Comparator B Output		
8	VDD	Positive Supply Voltage		

Function Table



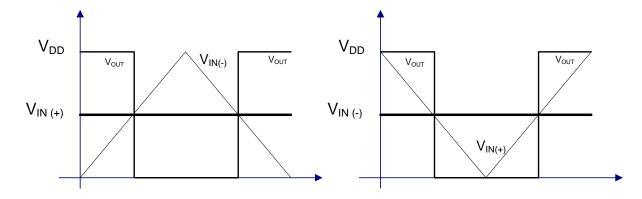


Figure 3. V_{IN} vs. V_{OUT}

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Condition	Min.	Max.	Unit	
V _{DD} to V _{SS}	Supply Voltage		-3.0	+3.0	V	
V DD 10 V SS	Supply Vollage		0	6.0	V 	
DV _{IN}	Differential Input Voltage			±6		
V _{IN}	Input Voltage			V _{SS} to V _{DD}	V	
ts	Output Short Circuit Duration ⁽¹⁾			Indefinite	S	
TJ	Junction Temperature			+150	°C	
T _{STG}	Storage Temperature Range		-65	+150	°C	
P _D	Pow er Dissipation			226	mW	
ΘJA	Thermal Resistance			287	°C/W	
	IEC 61000 4 3 System ESD	Air Gap		15		
	IEC 61000-4-2 System ESD	Contact		8		
	IEDEO IEODOO AAAA I kaasaa Dadka	All Pins		8		
ESD	JEDEC JESD22-A114, Human Body Model	Pin to Pin: IN(-), IN(+) to V_{DD} or V_{SS}		12	kV	
	JEDEC JESD22-C1 01, Charged Device Model	All Pins		2		

Note:

1. The maximum total power dissipation must not be exceeded.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. ON Semiconductor does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Condition	Min.	Max.	Unit	
V _{DD} to V _{SS}	Pow er Supply		-2.75	+2.75	V	
V DD 10 V 55	Tower Supply		0	5.5	V	
V_{DD}	Pow er Supply	V _{SS} =0V	1.6	5.5	V	
V _{IN}	Input Voltage			V_{SS} to V_{DD}	V	
		V _{DD} =5.0V		5		
IOH/IOL	Output Sink/Source Current	V _{DD} =3.0V		3	mA	
		V _{DD} =1.6V		1		
TA	Operating Temperature, Free Air		-40	+85	°C	

Electrical Characteristics

Symbol	Parameter	Condition	Min.	Тур.	Max.	Unit
/ _{DD} =5.5V, V ₅	SS=GND, and T _A =+25°C	1			1	
V _{HYS}	Input Hysteresis	V _{CM} =0.5V _{DD}		4		mV
V _{IO}	Input Offset Voltage(2)	V _{CM} =0.5V _{DD}	-15	±1	+15	mV
lιο	Input Offset Current			10		pА
lı	Input Bias Current			10		pА
V _{CM}	Common Mode Input Voltage		Vss		V_{DD}	V
CMRR	Common Mode Rejection Ratio (3)	V _{CM} =V _{DD}		68		dB
l _{DD}	Supply Current - Per Comparator			7	17	μA
PSRR	Pow er Supply Rejection Ratio (3)	$\Delta V_{DD}=0.5V$	45	80		dB
		V _O =V _{DD}		60		_
los	Output Short Circuit Current	Vo=Vss		90		mA
V _{OL}	Low -Level Output Voltage	I _{SINK} =5.0mA		0.1	0.3	V
VoH	High-Level Output Voltage	Isource=5.0mA	5.2	5.4		V
t _{PLH}	Propagation Delay (Turn-On)	Overdrive=20mV, C _L =15pF		0.40		μs
t _{PHL}	Propagation Delay (Turn-Off)	Overdrive=20mV, C _L =15pF		0.42		μs
tтьн	Daniel Dia (5-11(4)	C _L =50pF		4.0 5.4		ns
t _{THL}	Response Time, Output Rise/Fall ⁽⁴⁾					
/ _{DD} =3V, V _{SS} :	=GND, and T _A =+25°C	II.				
V _{HYS}	Input Hysteresis	V _{CM} =0.5V _{DD}		4		mV
V _{IO}	Input Offset Voltage(2)	V _{CM} =0.5V _{DD}	-15	±1	+15	mV
I _{IO}	Input Offset Current			10		рА
lı	Input Bias Current			10		рА
V _{CM}	Common Mode Input Voltage		Vss		V_{DD}	V
CMRR	Common Mode Rejection Ratio (3)	V _{CM} =V _{DD}		60		dB
I _{DD}	Supply Current(x) Per Comparator			6	15	μΑ
PSRR	Pow er Supply Rejection Ratio (3)	ΔV _{DD} =0.5V	45	70		dB
	Output Short Circuit Current	V _O =V _{DD}		27		mA
los		Vo=Vss		35		
V _{OL}	Low -Level Output Voltage	I _{SINK} =3.0mA		0.15	0.35	V
V _{OH}	High-Level Output Voltage	I _{SOURCE} =3.0mA	2.65	2.85		V
tpLH	Propagation Delay (Turn-On)	Overdrive=20mV, C _L =15pF		0.45		μs
t _{PHL}	Propagation Delay (Turn-Off)	Overdrive=20mV, C _L =15pF		0.47		μs
tтьн	Bassanas Timas Outrant Biss /F (4)	0 50-5		6.1		
t _{THL}	Response Time, Output Rise/Fall ⁽⁴⁾	C _L =50pF	—	6.2	 	_ ns

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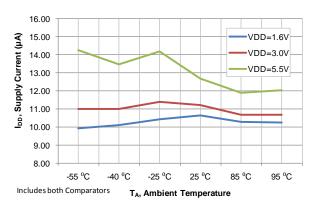
Electrical Characteristics

Symbol	Parameter	Condition	Min.	Тур.	Max.	Unit
V _{DD} =1.6V, V _S	SS=GND, and T _A =+25°C			1	·!!	
V _{HYS}	Input Hysteresis	V _{CM} =0.5V _{DD}		3.5		mV
V _{IO}	Input Offset Voltage(2)	V _{CM} =0.5V _{DD}	-15	±1	+15	mV
lio	Input Offset Current			10		рА
lı	Input Bias Current			10		рА
V _{CM}	Common Mode Input Voltage		Vss		V_{DD}	V
CMRR	Common Mode Rejection Ratio (3)	V _{CM} =V _{DD}		56		dB
l _{DD}	Supply Current(x) Per Comparator			5	13	μΑ
PSRR	Pow er Supply Rejection Ratio (3)	ΔV_{DD} =0.5V	45	70		dB
1	Outrot Chart Cinevit Comment	V _O =V _{DD}		5.5		A
los	Output Short Circuit Current	V _O =V _{SS}		7.5		mA
V_{OL}	Low -Level Output Voltage	I _{SINK} =1.0mA		0.15	0.25	V
VoH	High-Level Output Voltage	Isource=1.0mA	1.35	1.50		V
tpLH	Propagation Delay (Turn-On)	Overdrive=20mV, C _L =15pF		0.52		μs
t _{PHL}	Propagation Delay (Turn-Off)	Overdrive=20mV, C _L =15pF		0.54		μs
t⊤∟н	Response Time, Output Rise/Fall ⁽⁴⁾	C _L =50pF		16.5		ns
t _{THL}	- Nesponse Time, Output Nise/Fall	OL-30PF		13.0		1113

Notes:

- Differential input switching level is guaranteed at the minimum or maximum offset voltage, minus or plus half the maximum hysteresis voltage.
- 3. Guaranteed by design and characterization data
- 4. Input signal: 1kHz, square-wave signal with 10ns edge rate.

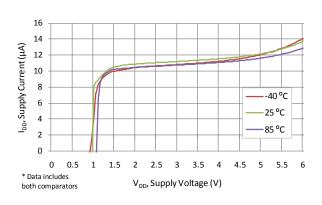
Typical Performance Characteristics



900 800 1.6 VDD 700 3.0 VDD 600 5.5 VDD 500 3 400 300 200 100 0 0.01 Temp. =25C 0.1 10 100 1000 Frequency (Khz)

Figure 4. Supply Current vs. Temperature

Figure 5. Supply Current vs. Output Transition Frequency



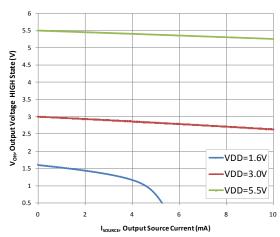
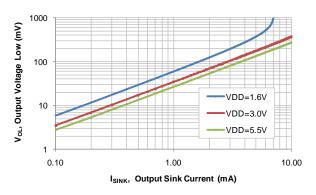


Figure 6. Supply Current vs. Supply Voltage

Figure 7. Output HIGH vs. Output Drive Current



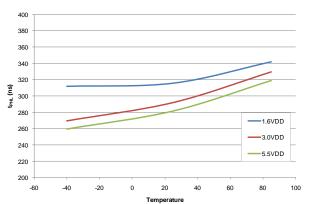
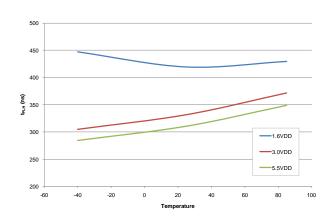


Figure 8. Output LOW vs. Output Drive Current

Figure 9. Propagation Delay (tPHL) vs. Temperature

Typical Performance Characteristics (Continued)



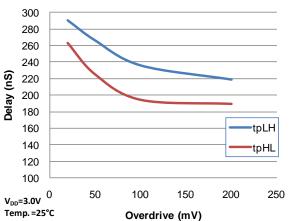
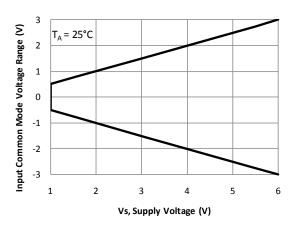


Figure 10.Propagation Delay (t_{PLH}) vs. Temperature

Figure 11. Propagation Delay vs. Input Overdrive



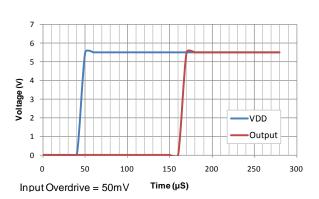
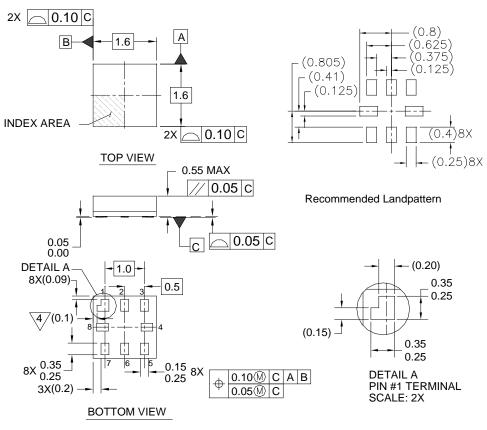


Figure 12. Input Common Mode Voltage Range vs. Supply Voltage

Figure 13. Power-Up Delay

Physical Dimensions



Notes:

- 1. PACKAGE CONFORMS TO JEDEC MO-255 VARIATION UAAD
- 2. DIMENSIONS ARE IN MILLIMETERS
- 3. DRAWING CONFORMS TO ASME Y.14M-1994
- 4/PIN 1 FLAG, END OF PACKAGE OFFSET
 - 5. DRAWING FILE NAME: MKT-MAC08AREV4

MAC08AREV4

Figure 14. 8-Lead, MicroPak™ 1.6mm Wide

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